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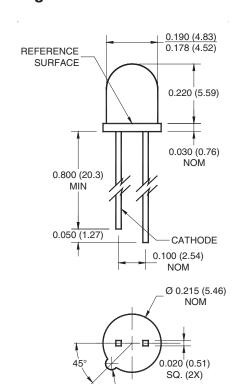


# QED422, QED423 Plastic Infrared Light Emitting Diode

## **Features**

- $\lambda$ = 880 nm
- Chip material = AlGaAs
- Package type: Plastic TO-46
- Matched Photosensor: QSD722/723/724
- Medium Wide Emission Angle, 30°
- High Output Power
- Package material and color: clear, purple tinted, plastic

## **Package Dimensions**



## NOTES:

1. Dimensions for all drawings are in inches (mm).

R 0.022 (0.56)

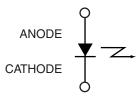
2. Tolerance of ± .010 (.25) on all non-nominal dimensions unless otherwise specified.

## **Description**

The QED422/423 is an 880 nm AlGaAs LED encapsulated in a clear, purple tinted, plastic TO-46 package.



## **Schematic**



## **Absolute Maximum Ratings** (T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Rating	Unit
Operating Temperature	T <sub>OPR</sub>	-40 to + 100	°C
Storage Temperature	T <sub>STG</sub>	-40 to + 100	°C
Soldering Temperature (Iron) <sup>(2,3,4)</sup>	T <sub>SOL-I</sub>	240 for 5 sec	°C
Soldering Temperature (Flow) <sup>(2,3)</sup>	T <sub>SOL-F</sub>	260 for 10 sec	°C
Continuous Forward Current	IF	100	mA
Reverse Voltage	V <sub>R</sub>	5	V
Power Dissipation <sup>(1)</sup>	P <sub>D</sub>	200	mW

## Notes:

- 1. Derate power dissipation linearly 2.67 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6 mm) minimum from housing

## **Electrical/Optical Characteristics** $(T_A = 25^{\circ}C)$

Parameter	Test Conditions	Symbol	Min	Тур	Max	Units
Peak Emission Wavelength	I <sub>F</sub> = 100 mA	λ <sub>PE</sub>	_	880	_	nm
Emission Angle	I <sub>F</sub> = 100 mA	2Θ1/2	_	30	_	Deg.
Forward Voltage	I <sub>F</sub> = 100 mA, tp = 20 ms	V <sub>F</sub>	_	_	1.8	V
Reverse Current	V <sub>R</sub> = 5 V	I <sub>R</sub>	_	_	10	μΑ
Radiant Intensity QEC422	I <sub>F</sub> = 100 mA, tp = 20 ms	I <sub>E</sub>	10	_	40	mW/sr
Radiant Intensity QEC423	I <sub>F</sub> = 100 mA, tp = 20 ms	Ι <sub>Ε</sub>	20	_	_	mW/sr
Rise Time	I <sub>F</sub> = 100 mA	t <sub>r</sub>	_	800	_	ns
Fall Time		t <sub>f</sub>	_	800	_	ns

Fig. 1 Normalized Radiant Intensity vs. Forward Current

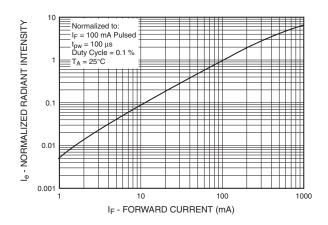


Fig. 2 Forward Voltage vs. Ambient Temperature

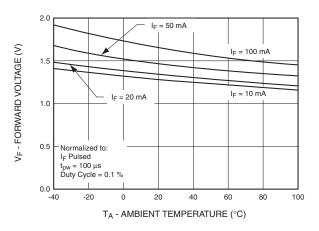


Fig. 3 Normalized Radiant Intensity vs. Wavelength

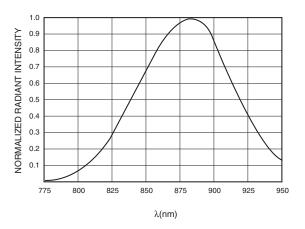
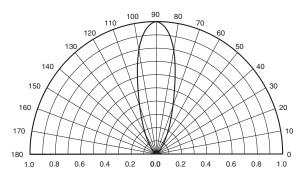


Fig. 4 Radiation Diagram



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CROSSVOLT™	GTO™ .	MICROWIRE™	Quiet Series™	UHC™
DOME™	HiSeC™	MSX™	RapidConfigure™	$UltraFET^{ ext{@}}$
EcoSPARK™	I <sup>2</sup> C <sup>TM</sup>	MSXPro™	RapidConnect™	UniFET™
E <sup>2</sup> CMOS <sup>TM</sup>	i-Lo™	OCX™	μSerDes™	VCX <sup>TM</sup>
EnSigna™	ImpliedDisconnect™	OCXPro™	SILENT SWITCHER <sup>®</sup>	Wire™
FACT™	IntelliMAX™	OPTOLOGIC <sup>®</sup>	SMART START™	
FACT Quiet Serie		OPTOPLANAR™	SPM™	
Aaraaa tha baara	Around the world TM	PACMAN™	Stealth™	
The Power France	I. Around the world.™	POP™	SuperFET™	
		Power247™	SuperSOT™-3	
Programmable A	cuve Droop	PowerEdge™	SuperSOT™-6	

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